NSN 5961-01-096-0184

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View Online at https://aerobasegroup.com/nsn/5961-01-096-0184 **Inclosure Material:** Metal **Overall Length:** 0.410 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 25.00 amperes forward current, average of standard range and 260.00 amperes source cutoff current outside diameter **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector outside diameter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface gold **Precious Material: Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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